



Features

- Frequency:1-20GHz
- Insertion Loss: 0.3dB (typ.)
- Limit Power:16dBm
- Tolerance Power:37dBm(CW)
- Input/Output: 50Ω
- Die Size: 1.42x0.6x 0.1 mm

Typical Applications

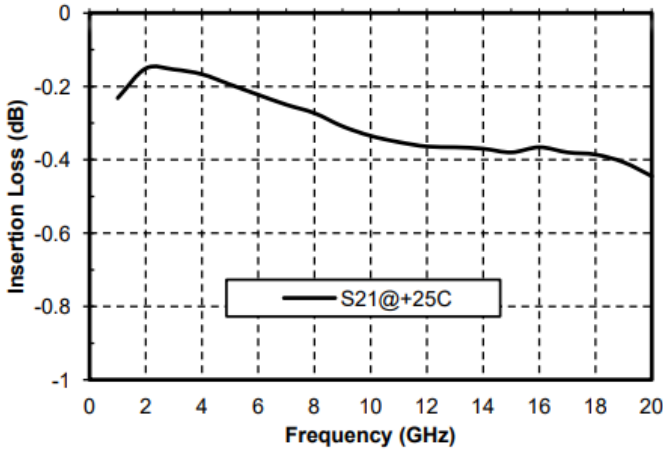
- Test Instrumentation
- Microwave Radio & VSAT
- Military & Space
- Telecom Infrastructure
- Fiber Optics

Electrical Specifications

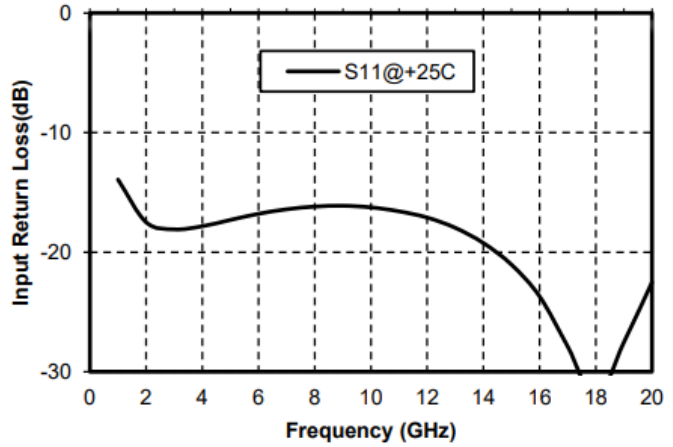
TA = +25°C

Parameters	Min.	Typ.	Max.	Units
Frequency	1-20			GHz
Insertion Loss	-	0.4	-	dB
Input Return Loss	-	19	-	dB
Output Return Loss	-	18	-	dB
Limit Power	-	16	-	dBm
Tolerance Power		37		dBm

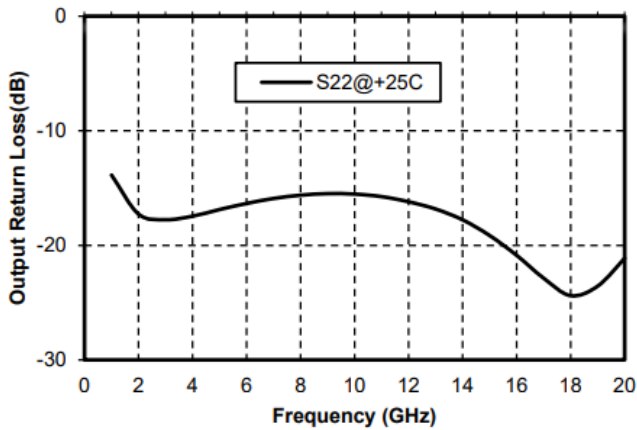
Insertion Loss Vs. Frequency



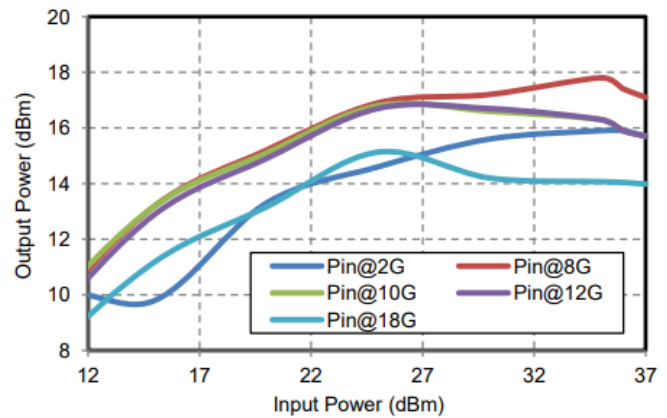
Input Return Loss Vs. Frequency



Output Return Loss Vs. Frequency



Limit Power @2G、8G、10G、12G&18G





Outline Drawing:

All Dimensions in um, tolerance range $\pm 50\mu\text{m}$



Pad Description

PAD	Function	Description
1	RF COMM	RF signal input, No DC blocking capacitor, external DC-blocking capacitor required
2	RF OUTPUT	RF signal output, with DC blocking capacitor
Die Bottom	GND	Die bottom must be connected to RF/DC ground.



Assembly Drawing



Notes:

1. Die thickness: 100um
2. Typical bond pad is 100*100 μm^2
3. Bond pad metalization: Gold
4. Backside metalization: Gold
5. Backside of the die (GND)
6. No connection required for unlabeled bond pads

Maximum Ratings:

1. RF input power: +37dBm
2. Storage temperature: -65°C to +150°C
3. Operating temperature: -55°C to 125°C